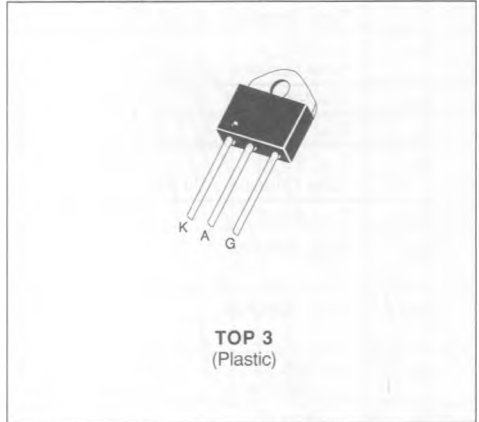


THYRISTORS

- GLASS PASSIVATED CHIP
- HIGH STABILITY AND RELIABILITY
- HIGH SURGE CAPABILITY
- HIGH ON-STATE CURRENT
- EASY MOUNTING ON HEATSINK
- ISOLATED PACKAGE :
INSULATING VOLTAGE 2500 V_{RMS}
- UL RECOGNIZED (E81734)


DESCRIPTION

General purpose SCR suited for power supplies up to 400 Hz on resistive or inductive loads.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		BTW69-200 → 800		BTW69-1000/1200		Unit
$I_{T(RMS)}$	RMS on-state Current (1)	$T_c = 70\text{ }^\circ\text{C}$	50				A
$I_{T(AV)}$	Mean on-state Current (1)	$T_c = 70\text{ }^\circ\text{C}$	32				A
I_{TSM}	Non Repetitive Surge Peak on-state Current (T_j initial = $25\text{ }^\circ\text{C}$) (2)	$t = 8.3\text{ ms}$	525	420			A
		$t = 10\text{ ms}$	500	400			
I^2t	I^2t Value for Fusing	$t = 10\text{ ms}$	1250	800			A ² s
di/dt	Critical Rate of Rise of on-state Current (3)		100				A/ μ s
T_{stg} T_j	Storage and Operating Junction Temperature Range		- 40 to 125				$^\circ\text{C}$ $^\circ\text{C}$

Symbol	Parameter	BTW69-						Unit
		200	400	600	800	1000	1200	
V_{DRM} V_{RRM}	Repetitive Peak off-state Voltage (4)	200	400	600	800	1000	1200	V

(1) Single phase circuit, 180° conduction angle.

(2) Half sine wave.

(3) $I_G = 800\text{ mA}$ $di_G/dt = 1\text{ A}/\mu\text{s}$

(4) $T_j = 125\text{ }^\circ\text{C}$

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction-case for D.C.	1	$^\circ\text{C}/\text{W}$
$R_{th(c-h)}$	Contact (case to heatsink)	0.20	$^\circ\text{C}/\text{W}$

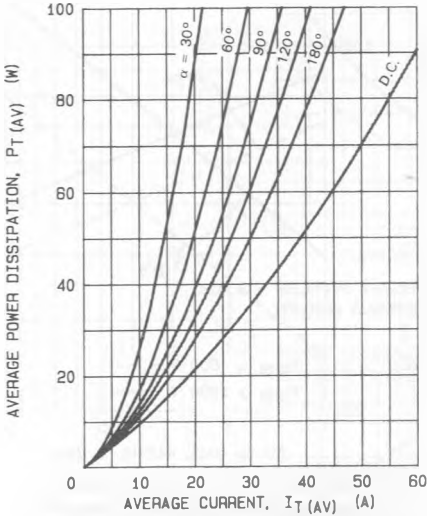
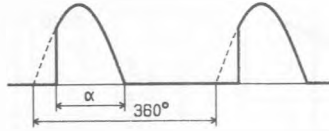


FIG.1 - MAXIMUM ON-STATE POWER DISSIPATION FOR SINUSOIDAL CURRENT WAVEFORM

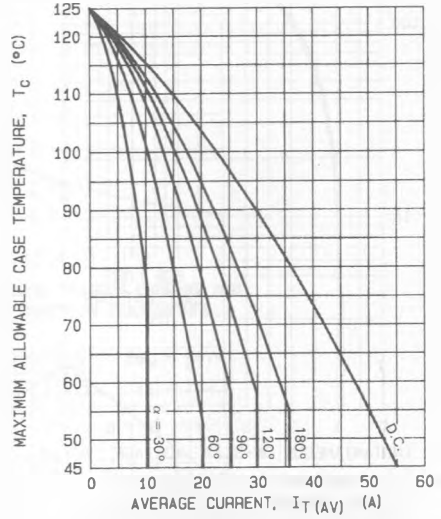


FIG.2 - MAXIMUM ALLOWABLE CASE TEMPERATURE FOR SINUSOIDAL CURRENT WAVEFORM

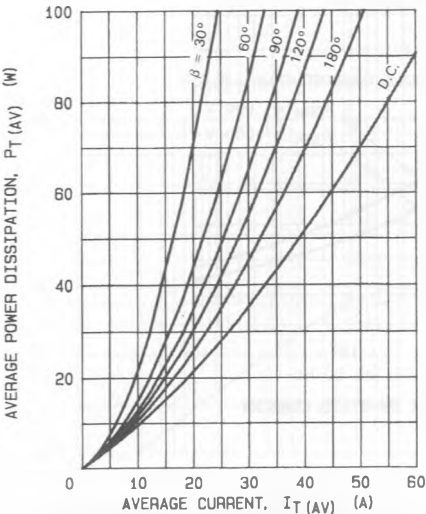
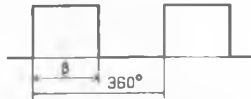


FIG.3 - MAXIMUM ON-STATE POWER DISSIPATION FOR RECTANGULAR CURRENT WAVEFORM

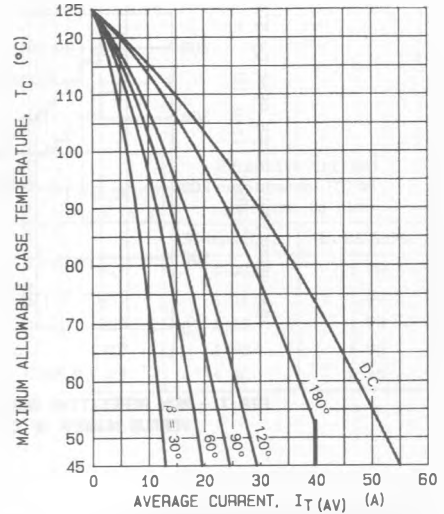


FIG.4 - MAXIMUM ALLOWABLE CASE TEMPERATURE FOR RECTANGULAR CURRENT WAVEFORM

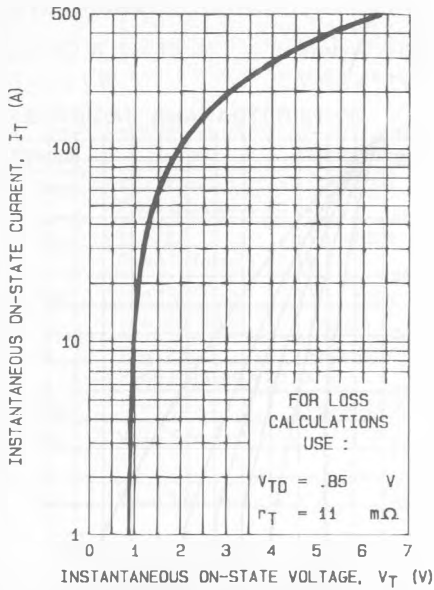


FIG.5 - MAXIMUM ON-STATE CONDUCTION CHARACTERISTIC ($T_J = 125^\circ\text{C}$).

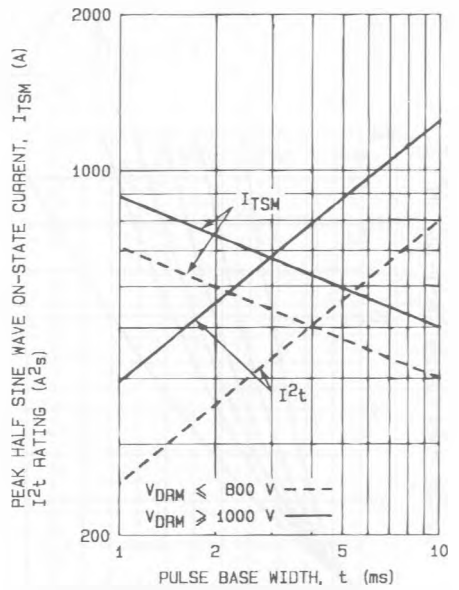


FIG.8 - NON REPETITIVE SUB-CYCLE SURGE ON-STATE CURRENT AND I^2t RATINGS (INITIAL $T_J = 25^\circ\text{C}$).

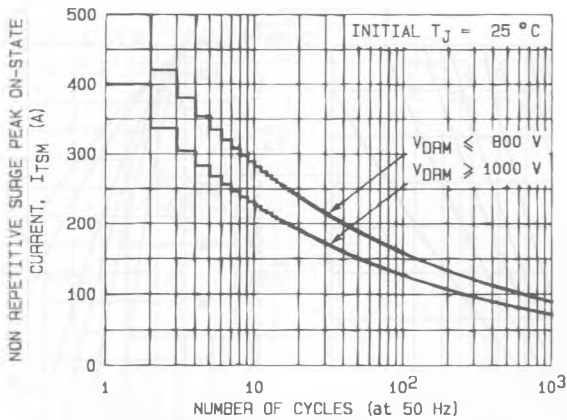


FIG.7 - NON REPETITIVE SURGE PEAK ON-STATE CURRENT VERSUS NUMBER OF CYCLES.

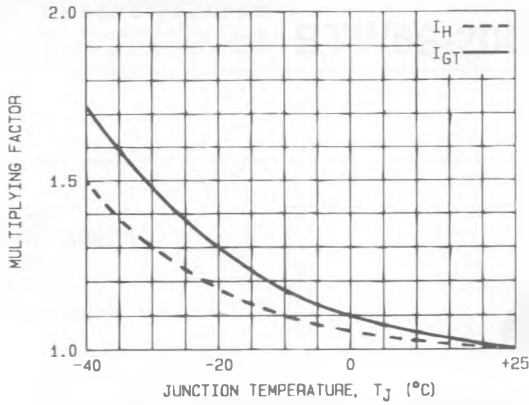


FIG. 8 - RELATIVE VARIATION OF GATE TRIGGER CURRENT AND HOLDING CURRENT VERSUS JUNCTION TEMPERATURE.

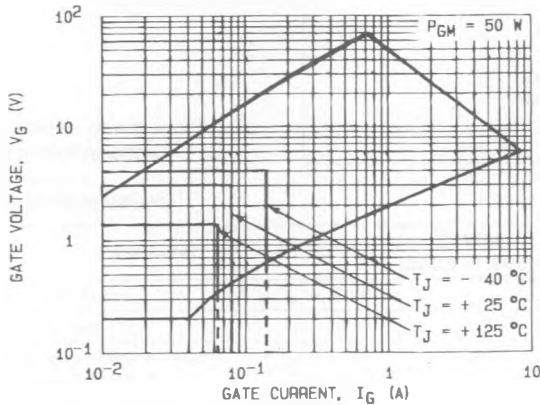


FIG. 9 - GATE TRIGGER CHARACTERISTICS.

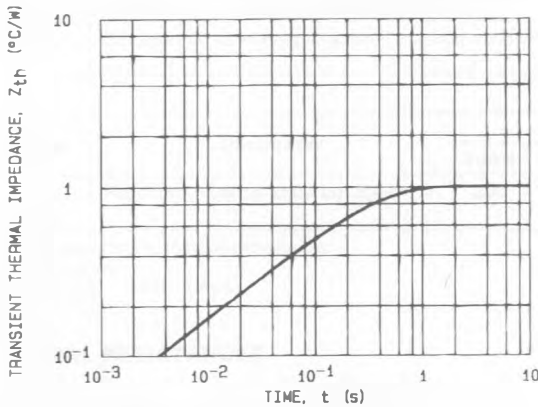


FIG.10 - TRANSIENT THERMAL IMPEDANCE JUNCTION TO CASE.

Conduction angle (α, β)	Effective thermal resistance ($^{\circ}\text{C}/\text{W}$) junction to case	
	Sinusoidal	Rectangular
180°	1.08	1.06
120°	1.12	1.50
90°	1.20	1.70
60°	1.40	1.90
30°	1.80	2.40